

# EMIF10-COM01F2

## 10-line IPAD™, EMI filter including ESD protection

#### **Features**

- EMI symmetrical (I/O) low-pass filter
- Lead free package
- Very low PCB space consuming: < 6 mm<sup>2</sup>
- Very thin package: 0.65 mm
- High efficiency in ESD suppression on both input & output pins
- High reliability offered by monolithic integration

#### Complies with the following standard:

- IEC 61000-4-2 level 4
  - 15 kV (air discharge)
  - 8 kV (contact discharge)

#### **Applications**

EMI filtering and ESD protection for:

- Computers and printers
- Communication systems
- Mobile phones

#### **Description**

The EMIF10-COM01F2 is a highly integrated device designed to suppress EMI / RFI noise in all systems subjected to electromagnetic interferences. The EMIF10 Flip-Chip packaging means the package size is equal to the die size.

Additionally, this filter includes an ESD protection circuitry which prevents damage to the application when subjected to ESD surges up to 15 kV.

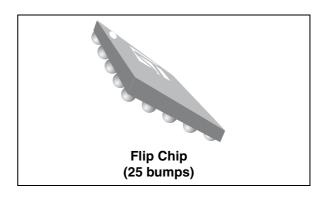


Figure 1. Pin configuration (bump side)

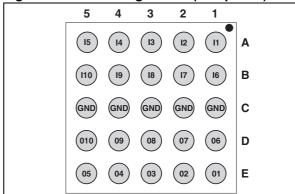
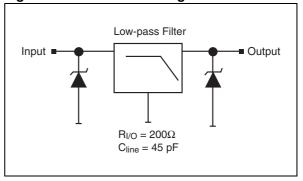


Figure 2. Basic cell configuration



TM: IPAD is a trademark of STMicroelectronics.

Characteristics EMIF10-COM01F2

# 1 Characteristics

Table 1. Absolute ratings ( $T_{amb} = 25 \, ^{\circ}C$ )

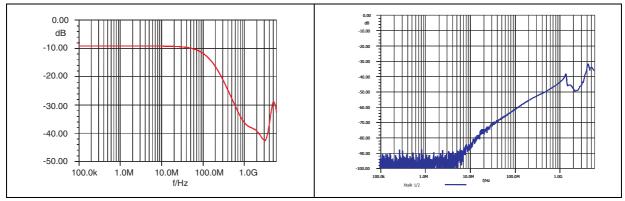
Symbol	Parameter and test conditions	Value	Unit
V <sub>PP</sub>	ESD discharge IEC61000-4-2, air discharge ESD discharge IEC61000-4-2, contact discharge	15 8	kV
T <sub>j</sub>	Junction temperature	125	°C
T <sub>op</sub>	Operating temperature range	- 40 to + 85	°C
T <sub>stg</sub>	Storage temperature range	- 55 to + 150	°C

Table 2. Electrical characteristics ( $T_{amb} = 25 \, ^{\circ}C$ )

Symbol	Parameter				A 1		
Symbol	i arameter				Ţ¹,		
$V_{BR}$	Breakdown voltage						
I <sub>RM</sub>	Leakage current @ V <sub>RM</sub>						
$V_{RM}$	Stand-off voltage						
V <sub>CL</sub>	Clamping voltage	V <sub>CL</sub>	V <sub>CL</sub> V <sub>BR</sub> V <sub>RM</sub>			V	
R <sub>d</sub>	Dynamic impedance				I <sub>R</sub>		
I <sub>PP</sub>	Peak pulse current						
R <sub>I/O</sub>	Resistance between Input and Output		slope:1/R <sub>d</sub>				
C <sub>line</sub>	Input capacitance per line				· I <sub>PP</sub>		
Symbol	Test conditions	М	in.	Тур.	Max.	Unit	
$V_{BR}$	I <sub>R</sub> = 1 mA	(	6	8	10	V	
I <sub>RM</sub>	V <sub>RM</sub> = 3 V per line				500	nA	
R <sub>d</sub>	$I_{PP} = 10 \text{ A}, t_p = 2.5 \mu \text{s}$			1		Ω	
R <sub>I/O</sub>		18	30	200	220	Ω	
C <sub>line</sub>	At 0 V bias			45	50	pF	
t <sub>LH</sub>	$V_{input} = 2.8 \text{ V}$ $R_{load} = 100 \text{ k}\Omega$				25	ns	

Figure 3. S21(db) attenuation measurement<sup>(1)</sup>

Figure 4. Analog crosstalk



<sup>1.</sup> Spikes at high frequencies are induced by the PCB layout

EMIF10-COM01F2 Characteristics

Figure 5. ESD response to IEC 61000-4-2 (+15 kV air discharge) on one input (V<sub>in</sub>) and on one output (V<sub>out</sub>)

Figure 6. ESD response to IEC 61000-4-2 (-15 kV air discharge) on one input (V<sub>in</sub>) and on one output (V<sub>out</sub>)

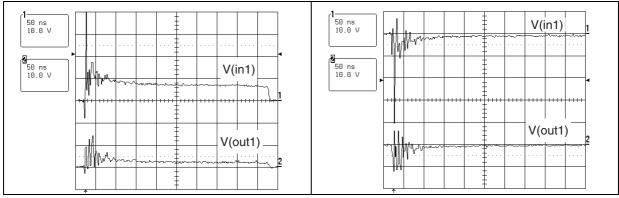


Figure 7. Rise time measurement

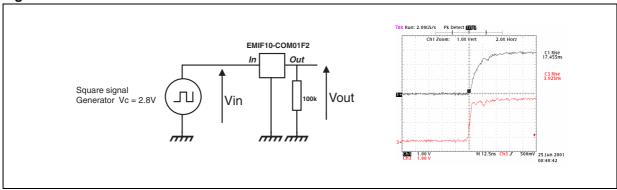
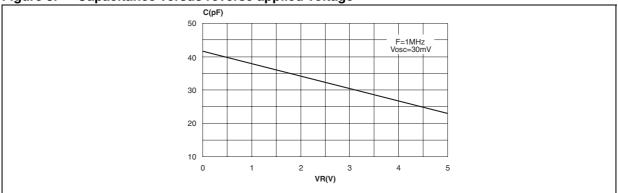


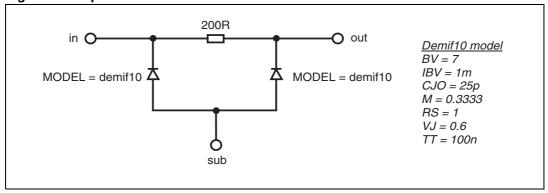
Figure 8. Capacitance versus reverse applied voltage



5/

## 2 Application information

Figure 9. Aplac model

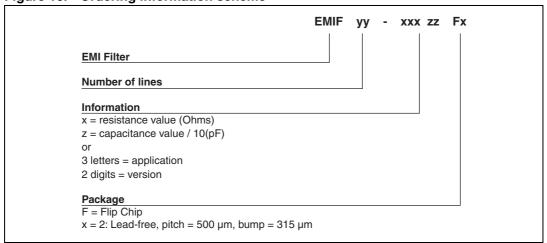


#### 2.1 PCB grounding recommendations

In order to ensure a good efficiency in terms of ESD protection and filtering behavior, we recommend to implement microvias (100  $\mu m$  dia.) between the GND bumps and the GND layer. GND bumps can be connected together in PCB layer 1, and in addition, if possible, use through hole vias (200  $\mu m$  dia.) in both sides of filter to improve contact to GND (layer). This layout will minimize the distance to the ground and thus parasitic inductances. In addition, we recommend to have GND plane wherever possible.

### 3 Ordering information scheme

Figure 10. Ordering information scheme



EMIF10-COM01F2 Package information

## 4 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at <a href="https://www.st.com">www.st.com</a>.

Figure 11. Flip Chip package dimensions

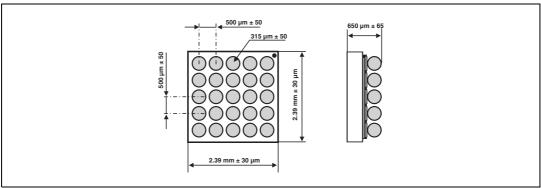
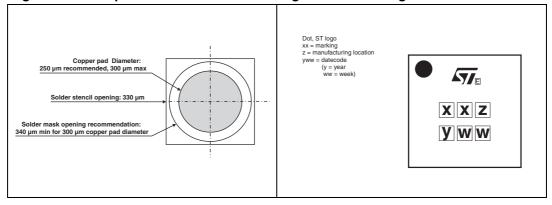


Figure 12. Footprint recommendations Figure 13. Marking



577

Ordering information EMIF10-COM01F2

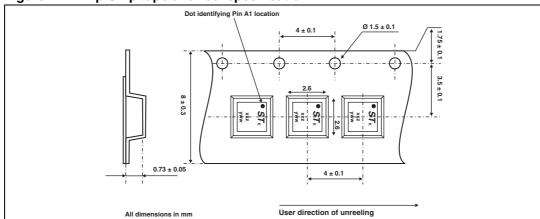


Figure 14. Flip Chip tape and reel specification

# 5 Ordering information

Table 3. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
EMIF10-COM01F2	FE	Flip Chip	8.3 mg	5000	Tape and reel

Note: More information is available in the application notes:

AN1235: "Flip Chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

# 6 Revision history

Table 4. Document revision history

Date	Revision	Description of changes
14-Dec-2004	1	First issue.
08-Apr-2005	2	Die shrink.
19-Oct-2005	3	Replaced Figures 3 and 13. Added ECOPACK statement.
03-Apr-2006	4	Reformatted to current standard. Pin identification in Figure 1 updated.
17-Apr-2008	5	Updated ECOPACK statement. Updated Figure 10, Figure 11 and Figure 14. Reformatted to current standards.

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